

Introduction to Nanotechnology

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Ph.D. 1989 Harvard University

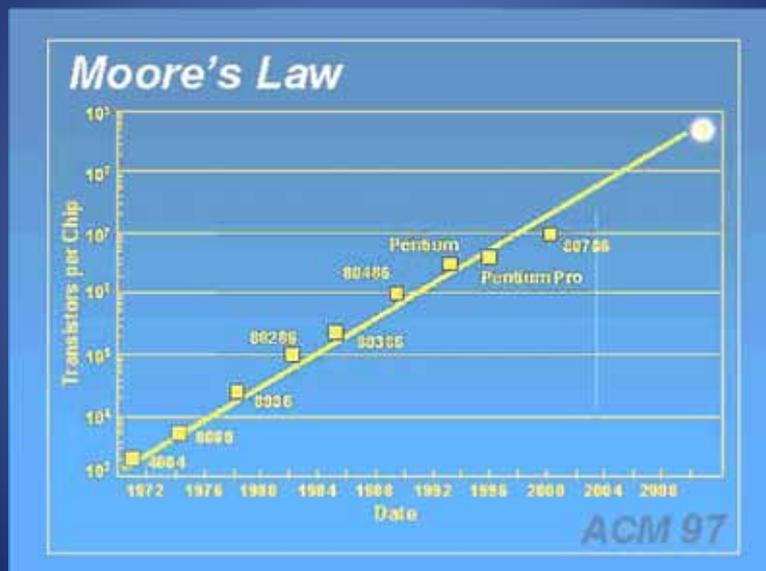
Hossein hosseinkhani: GIBE, NTUST
Ph.D. Kyoto University

Chunwei Chen: MSE, NTU
Ph.D. Cambridge University

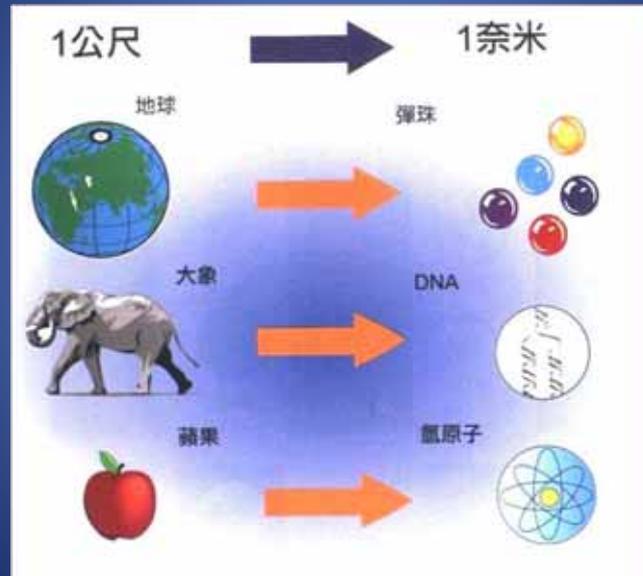
Li-Chyong Chen: CCMS, NTU
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Moore's Law



What is Nano?



Scale

- Meter (m)
- Millimeter (mm) = 10^{-3} m
- Micrometer (μm) = 10^{-6} m
- Nanometer (nm) = 10^{-9} m
- Picometer (pm) = 10^{-12} m
- Femtometer (fm) = 10^{-15} m
- Attometer (am) = 10^{-18} m ?
- Second (s)
- Millisecond (ms) = 10^{-3} s
- Microsecond (μs) = 10^{-6} s
- Nanosecond (ns) = 10^{-9} s
- Picosecond (ps) = 10^{-12} s
- Femtosecond (fs) = 10^{-15} s
- Attosecond (as) = 10^{-18} s

Pressure

- $1 \text{ Pa} = 1 \text{ Nm}^{-2} = 10^{-5} \text{ bar} = 7.501 * 10^{-3} \text{ mm Hg (torr)}$
- $1 \text{ atm} = 760 \text{ mm Hg} = 1.013 \text{ bar}$

Energy

- $1 \text{ cal} = 4.184 \text{ J}$
- $1 \text{ eV} = 1.602 * 10^{-19} \text{ J} = 23.06 \text{ kcal/mole}$
- $1 \text{ kWh} = 3.6 * 10^6 \text{ J}$
- $1 \text{ BTU} = 1055 \text{ J}$

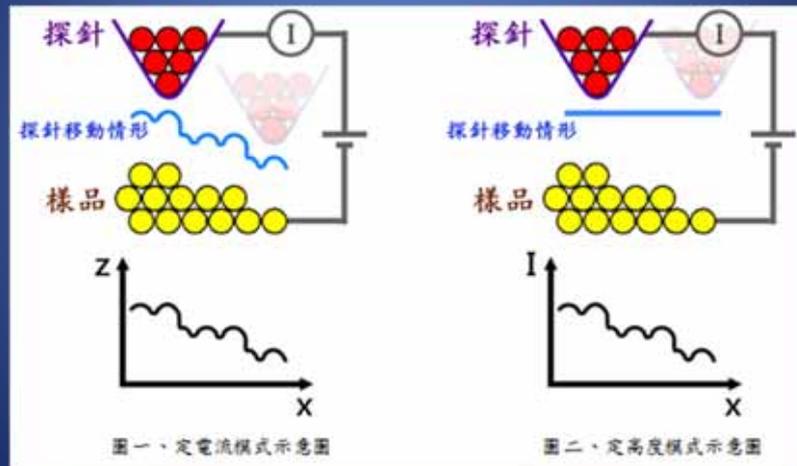
Power

- $1 \text{ W} = 1 \text{ Js}^{-1}$
- $1 \text{ hp} = 746 \text{ W}$

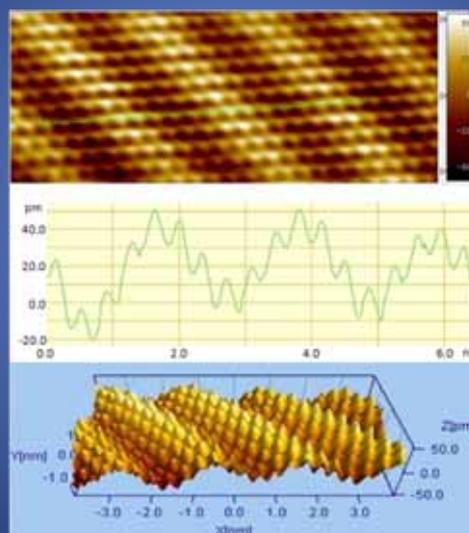
SEM



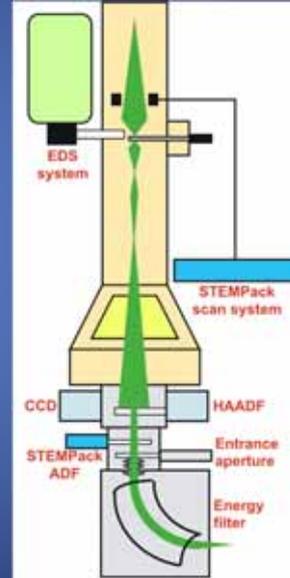
STM



STM



TEM



TEM (EELS)

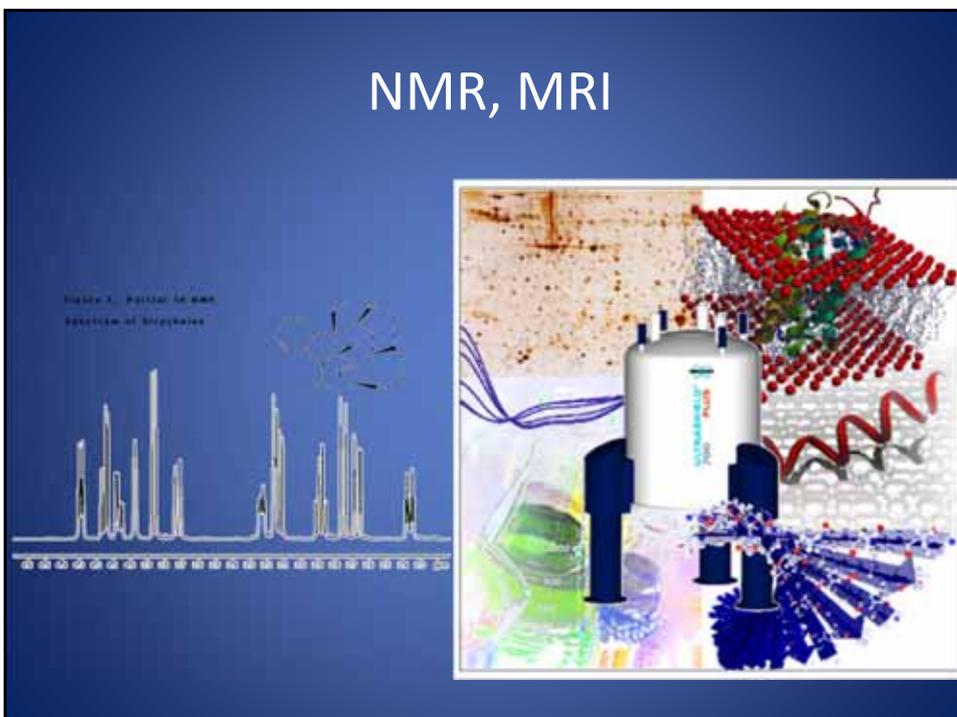
A diagram and images illustrating TEM (EELS) analysis. The diagram shows a specimen being analyzed by STEM (Scanning Transmission Electron Microscopy) and EELS (Electron Energy Loss Spectroscopy). The specimen is shown as a grid of atoms. The STEM beam is shown as a focused electron beam. The EELS signal is shown as a spectrum. The diagram also shows a DF (Dark-Field) image and an EELS spectrum. The EELS spectrum shows a peak at approximately 284 eV, corresponding to the carbon K-edge. The DF image shows a lattice of atoms. The EELS spectrum shows a peak at approximately 284 eV, corresponding to the carbon K-edge. The DF image shows a lattice of atoms. The EELS spectrum shows a peak at approximately 284 eV, corresponding to the carbon K-edge.

The diagram includes a schematic of the STEM/EELS setup, a graph of the EELS spectrum showing a peak at approximately 284 eV, and a high-resolution TEM image showing a lattice of atoms with a scale bar of 1.36 Å.

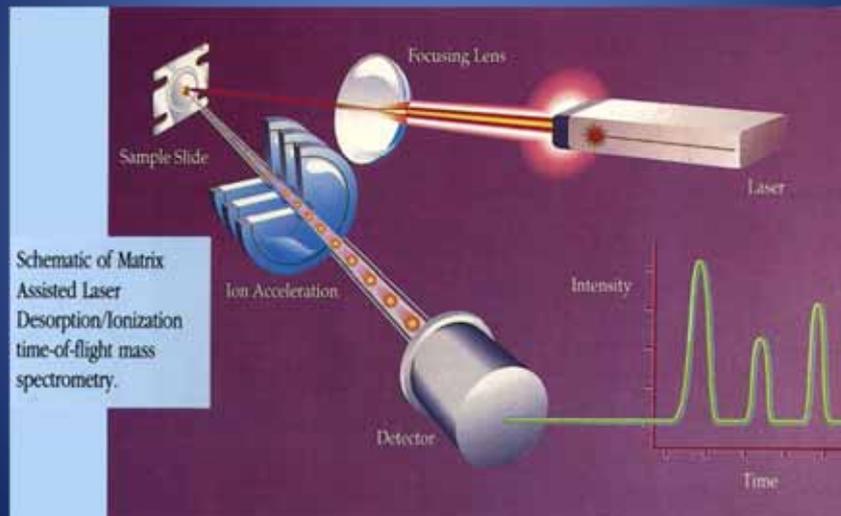
Composition Analysis

1. EL (元素分析儀)
2. EDS (X射線能量散佈分析儀)
3. AES (歐傑電子光譜)
4. NMR (核磁共振波譜分析)
5. ICP MASS (電子耦合電漿質譜)
6. MALDI (Matrix-assisted laser desorption/ionization)

NMR, MRI



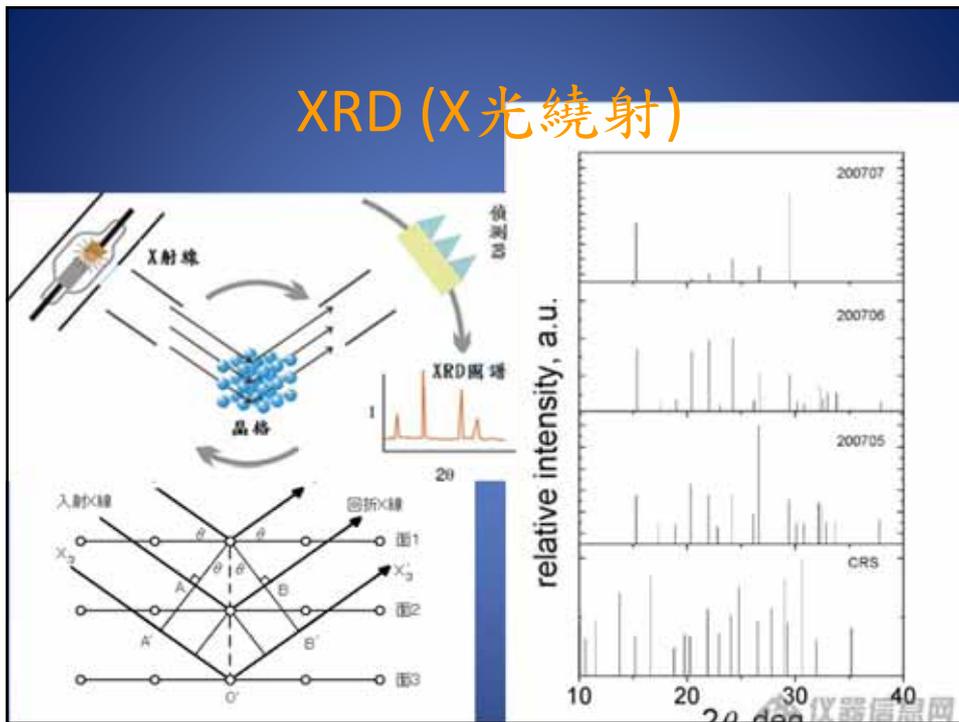
MALDI (Matrix-assisted laser desorption/ionization)



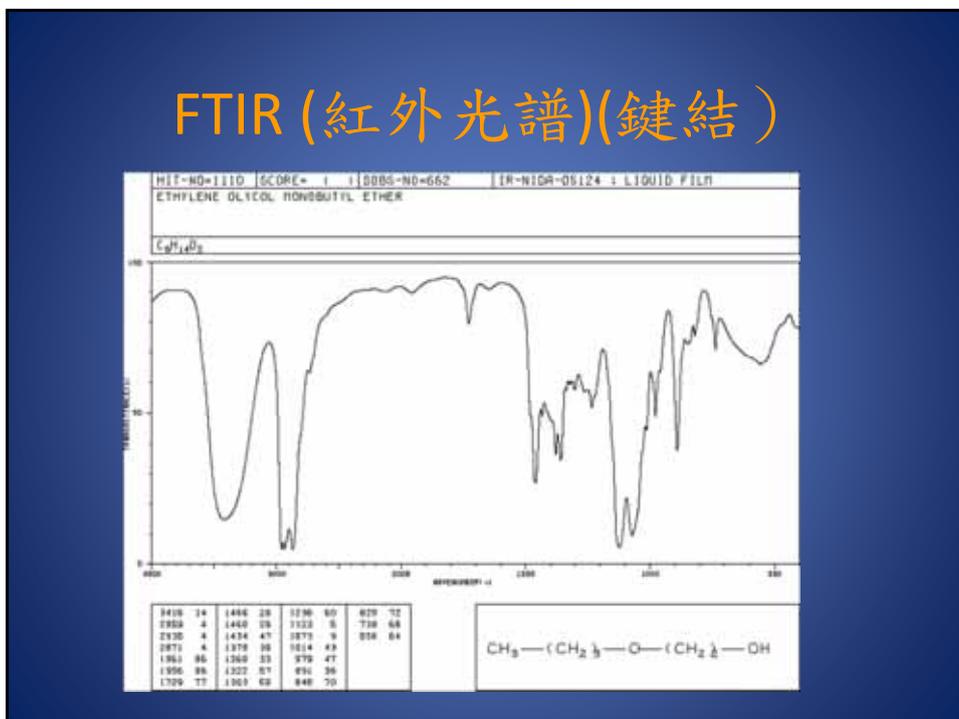
Structure Analysis

1. XRD (X光繞射)
2. TEM (穿透式電子顯微鏡)
3. FTIR (紅外光譜)
4. Raman (拉曼光譜)

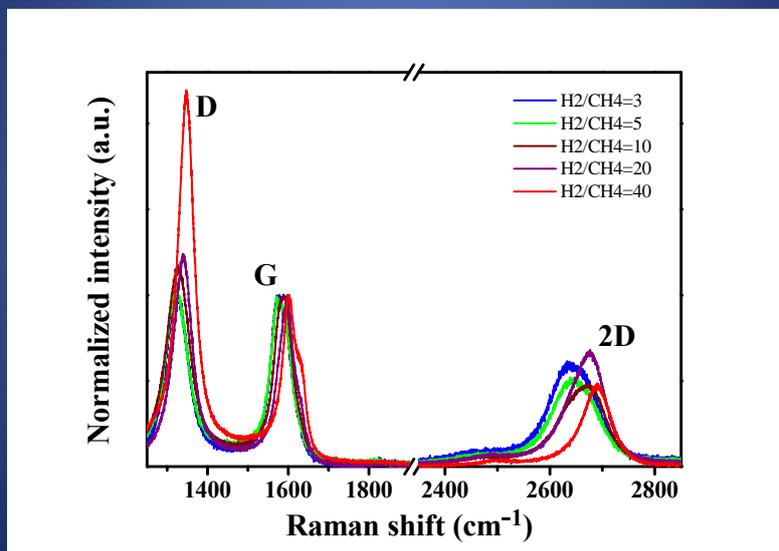
XRD (X光繞射)



FTIR (紅外光譜)(鍵結)



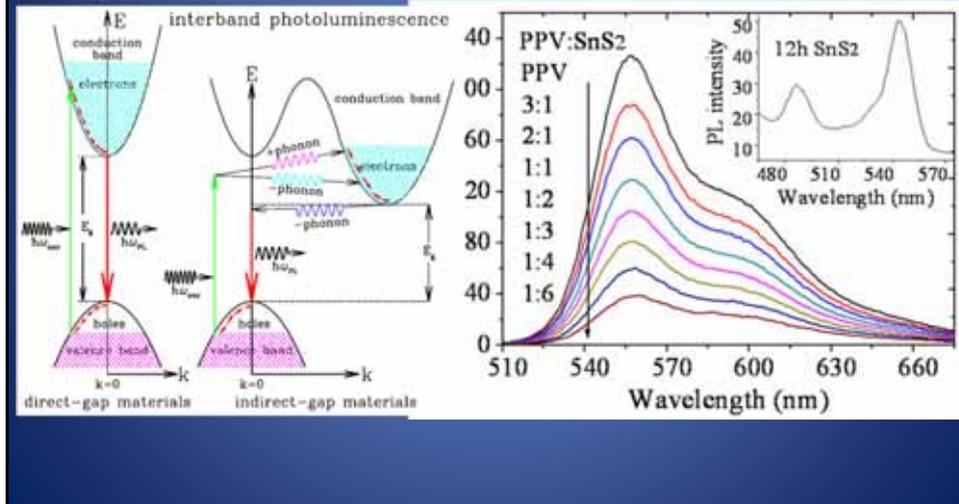
Raman (拉曼光譜)



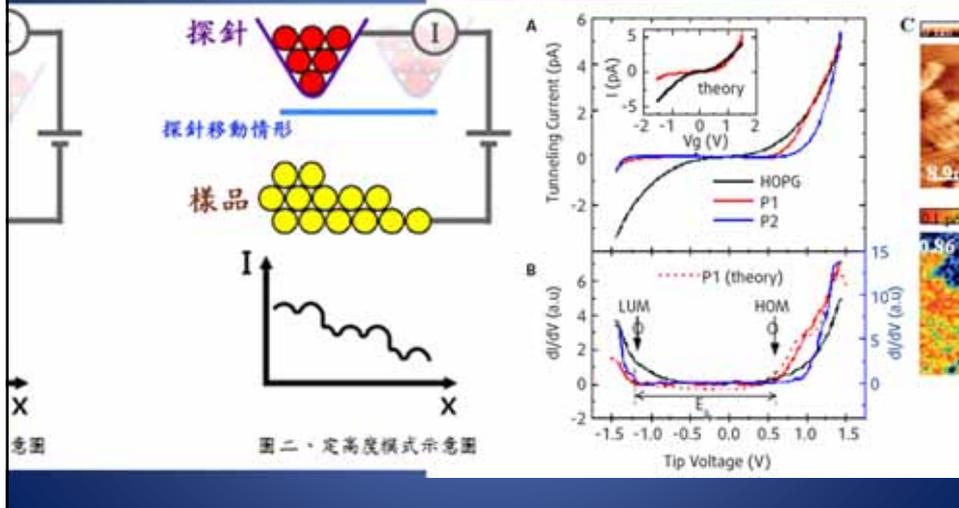
Electronic properties

1. Optical Absorption (吸收光譜)
2. Photoluminescence (螢光光譜)
3. STS (掃描穿隧顯微術)
4. XPS (X光電子光譜)
5. 同步輻射測量(SRRC)

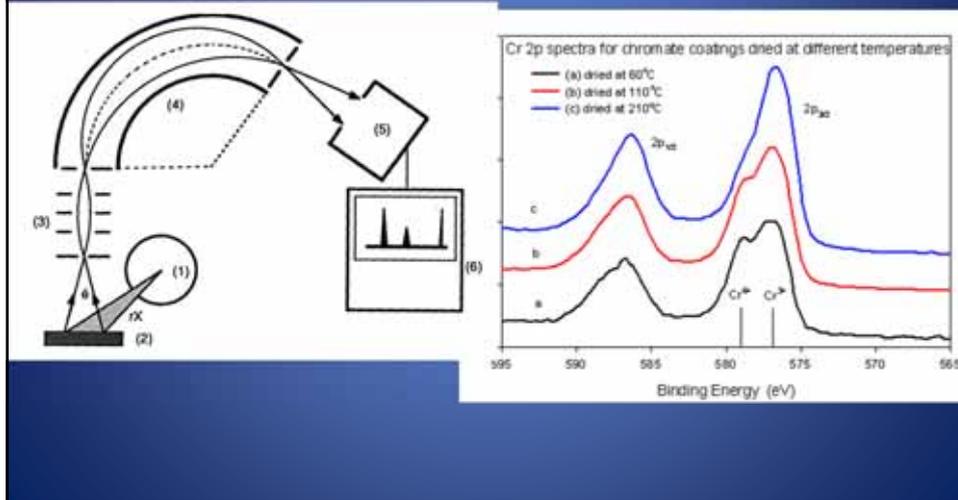
Photoluminescence (PL & CL)



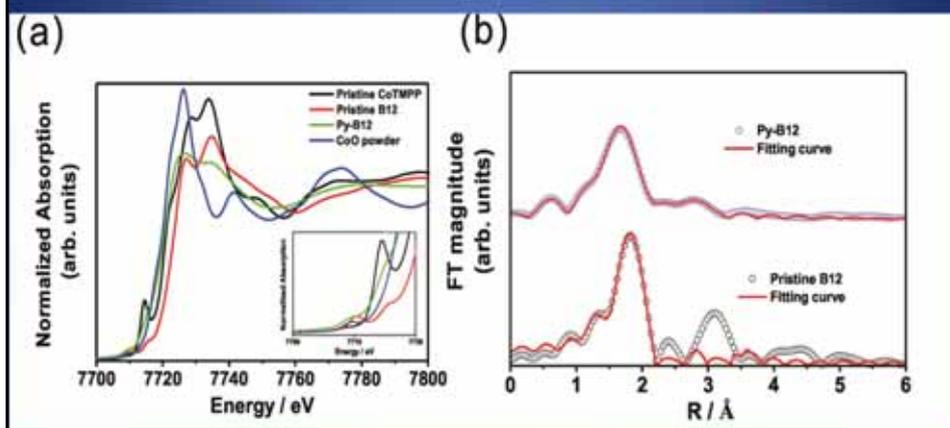
STS (掃描穿隧顯微術)



XPS (X光電子光譜)



同步輻射測量(SRRC)

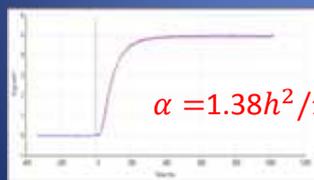
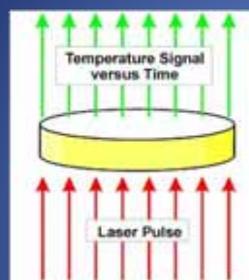


(XANES & EXAFS)

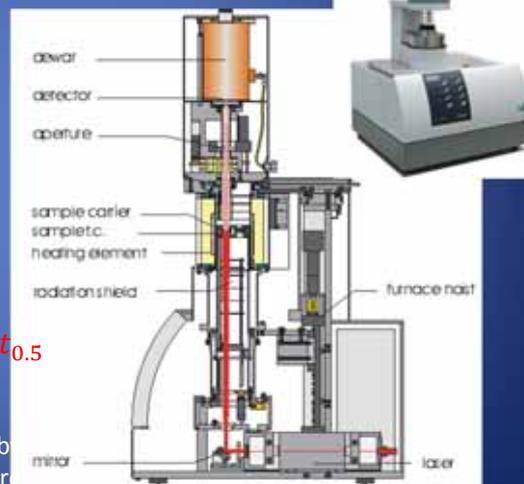
Other Thermal and Magnetic Measurements

1. 熱傳導係數測量(Thermal conductivity)
2. 熱重分析(TGA)
3. 熱分析儀 (DSC)

Thermal Diffusivity Measurement

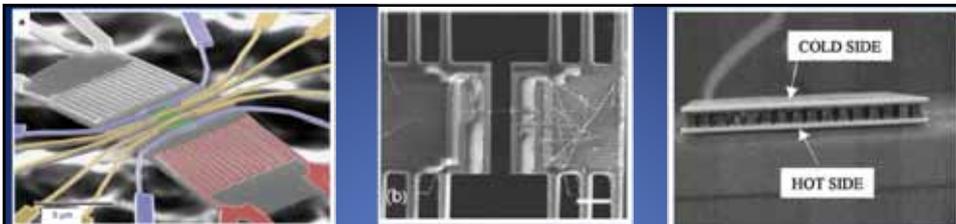
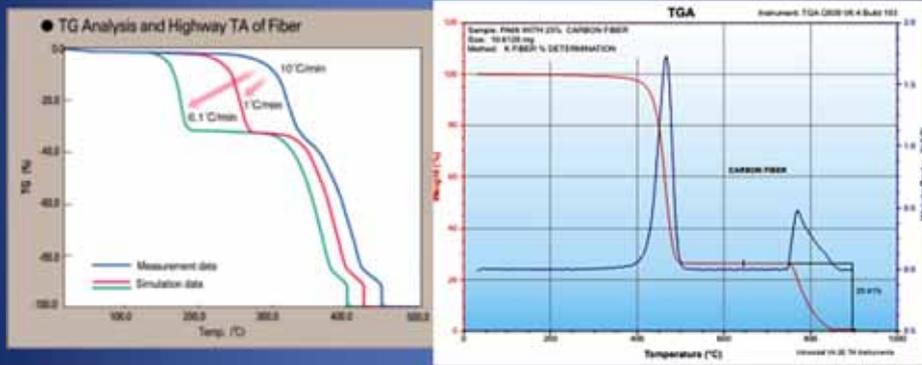


We can get the thermal diffusivity by measuring the “half-time” of temperature increase resulted from laser heating.

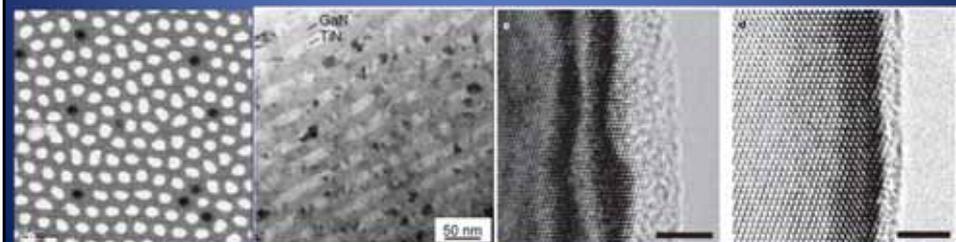


Cooperator: Dr. Y. Chen's lab

TGA & DSC



Nanomaterials for Thermoelectric Applications



Renewable Energy

Renewable Energy Consumption by Source

US DOE - EIA Annual Energy Survey 2006

Source	Consumption (Quadrillion Btu/Year)
Available Waste Heat	7.8
Hydroelectric Power	2.9
Wood	2.1
Biofuels	0.8
Wastes	0.4
Geothermal	0.3
Wind	0.3
Solar PV	0.1

*The quantities that is available are US National Total & is miles high at all.
 (1) 1.7 Quads of energy is used for industry - of this 10.8 percent is used in the form of Waste Heat (W.H.)
 (2) Geothermal hydroelectric power.
 (3) High sulfide and low sulfide consumption, plus losses and is products from the production of fuel ethanol and bioethanol.
 (4) Industrial solid waste from Biogenic sources, landfill gas, sludge waste, agricultural byproducts, and other biomass. Through 2005, distributed non-renewable waste (thermal) solid waste from non-biogenic sources, and the demand for it.

- Solar
- Wind
- Water
- Biomass
- Geothermal
- Hydrogen & Fuel Cells






Exhaust Waste Heat to Electrical Power

Typical Energy Split in Gasoline Internal Combustion Engines



GM has 350Watt avg systems on a truck can get 3% to 4% fuel saving with better integration.

www.greencarcongress.com/thermoelectrics

TE Generator Working Principle

The diagram illustrates the Seebeck effect. On the left, a red 'Heat Source' provides energy to the 'Hot side' of the device. This side consists of an n-type semiconductor (top) and a p-type semiconductor (bottom). On the right, the 'Cold side' is connected to an external circuit containing a load resistor. The circuit shows 'Current' flowing out of the positive terminal (+) and into the negative terminal (-), with a voltage V_L across the resistor. Arrows indicate the movement of charge carriers: electrons (e^-) moving from the hot side to the cold side in the n-type material, and holes (h^+) moving from the hot side to the cold side in the p-type material.

Electron flow \rightarrow

Hole flow \rightarrow

Total current flow \rightarrow

Chen et al., Intl. Mater. Rev. 48(2003)45

TE Generator Working Principle

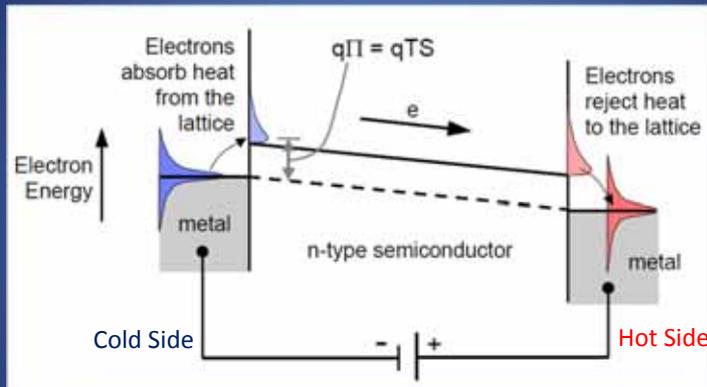
The Seebeck and the Peltier Effect

Thermoelectric Device

Thermoelectric Power Generation

Thermoelectric Cooling

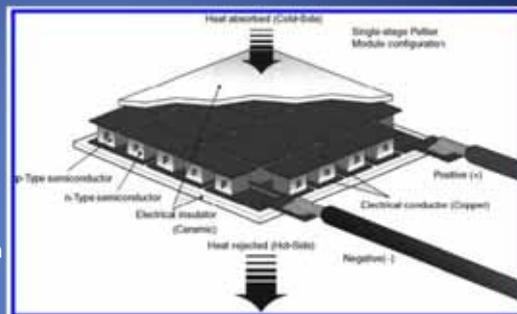
The Peltier Effect (1834)



Driven by an applied potential, electrons (holes) absorb heat from the lattice at the cold side, and reject heat to the lattice at the hot side
→ Refrigeration.

Benefits of Thermoelectric devices

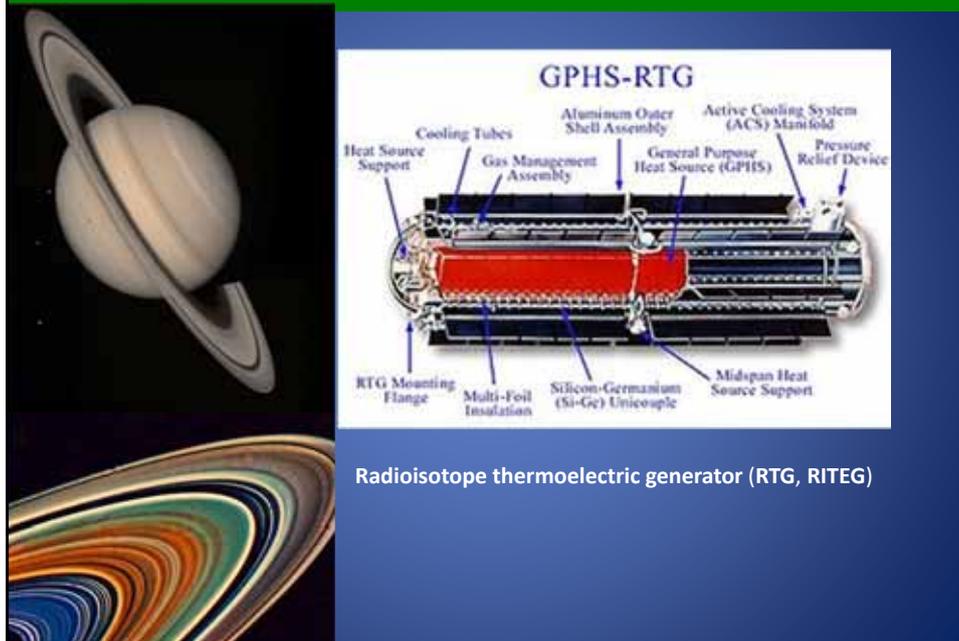
- ✓ No moving elements
- ✓ No working fluids and gases
- ✓ Low-noise operation
- ✓ Reduced size and weight
- ✓ High reliability — KRYOTHERM guarantees lifetimes of more than 200,000 hours for our TEDs
- ✓ Easy switching from cooling to heating mode



Example of TE Devices: Voyagers



Example of TE Devices: RTG

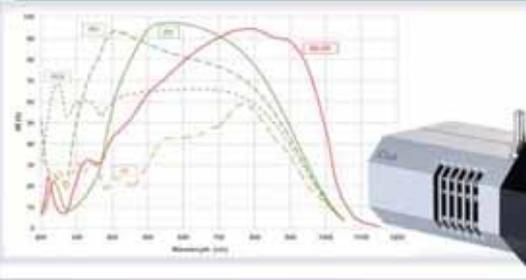


Example of TE Devices: CCD Cooling



Heat flows from the object being cooled through the Peltier module to the heat dissipation side.

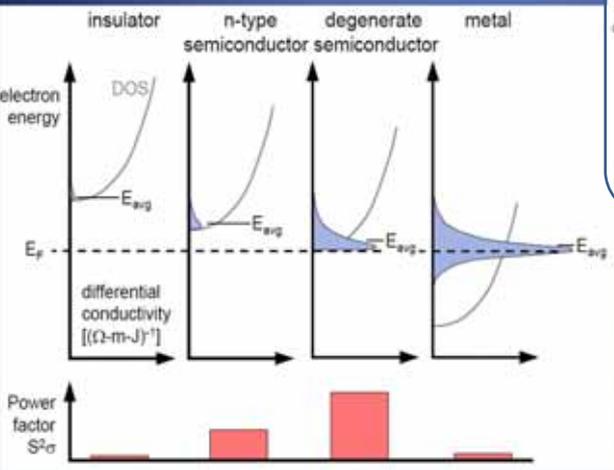






Koolatron P-27 Voyager - A Thermoelectric Cooler - 12 Volt Cooler (\$139.95)

Differential Electron Conductivity



insulator n-type semiconductor degenerate semiconductor metal

electron energy

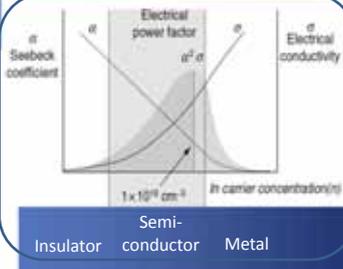
DOS

E_{avg}

E_F

differential conductivity $[(\Omega \cdot m \cdot J)^{-1}]$

Power factor $S^2 \sigma$



Seebeck coefficient α

Electrical power factor $\alpha^2 \sigma$

Electrical conductivity σ

$1 \times 10^{19} \text{ cm}^{-3}$ in carrier concentration (n)

Insulator Semi-conductor Metal

“Power factor”

$$ZT = \frac{S^2 \sigma}{k} T$$

Selection of Thermoelectric Materials

$$Z = \frac{S^2 \sigma}{\kappa}$$

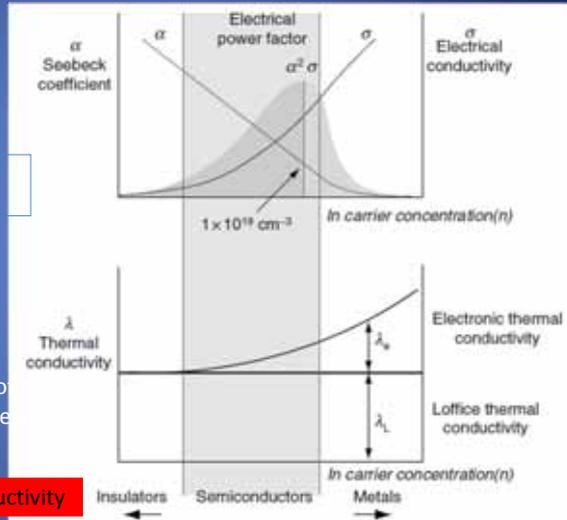
Electrical conductivity σ
 Thermal conductivity κ
 Seebeck coefficient S

Free carrier density n

The thermal conductivity
 $\kappa = \kappa_{Lattice} + \kappa_{Electron}$

Lattice part is roughly independent of n
 while the electronic part is directly related to the electrical conductivity

High power factor, Low thermal conductivity

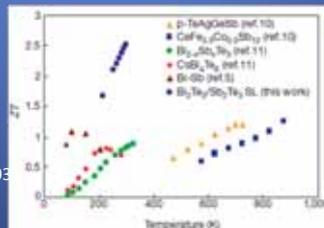


Schematic dependence of electrical conductivity, Seebeck coefficient, power factor, and thermal conductivity on concentration of free carriers.

ZT in This Decade

Year	Journal	Materials	ZT	T(K)	Institute
2011	Nature	PbTe _{1-x} Se _x (Buck)	1.8	850K	MS, California Institute of Technology
2009	Nature	In ₄ Se _{3-d} (Buck)	1.5	700K	Samsung
2008	Nature	Si (52nm rough NWs)	0.6	300K	Berkeley
2008	Nature	Si (20nm NWs)	1.0	200K	CE, California Institute of Technology
2008	Science	BiSeTe (buck)	1.5	400K	Physics, Boston College
2004	Science	AgPb _m SbTe _{2+m} (buck)	2.1	800K	Michigan State University
2003	Nature	Bi ₂ Te ₃ /Pb ₂ Te ₃ SL	2.6	300K	Research Triangle Institute
2002	Science	PbSeTe/PbTe SL	1.6	300K	Massachusetts Institute of Technology
Before			~1		

Y. Z Pei et al, Nature 473, 66 (2011)
 J. S. Rhyee et al, Nature 459, 965 (2009)
 A. I. Hochbaum et al, Nature 451, 163 (2008)
 A. I. Boukai et al, Nature 451, 168 (2008)
 B. Poudel et al, Science 320, 634 (2008)
 K. F. Hsu et al, Science 303, 818 (2004)
 R. Venkatasubramanian et al, Nature 413 597 (2003)
 T. C. Harman et al, Science 297, 2229 (2002)



Nature Materials	Publication
2011	4
2010	4
2003-2009	13

ZT & Efficiency

Efficiency η

$$\eta = \frac{T_H - T_C}{T_H} \frac{\sqrt{1 + ZT} - 1}{\sqrt{1 + ZT} + T_C/T_H}$$

Figure-of-merit ZT

$$ZT = T \frac{S^2 \sigma}{\kappa}$$

Thermal conductivity κ

$$\kappa = \kappa_L + \kappa_{el}$$

Efficiency examples

ZT	T_H/K	T_C/K	η
0.5	673	373	5.6%
1	673	373	9.4%
2	673	373	14.3%
3	673	373	17.4%
3	773	373	20.8%
3	873	373	23.6%

Thermal conductivity κ

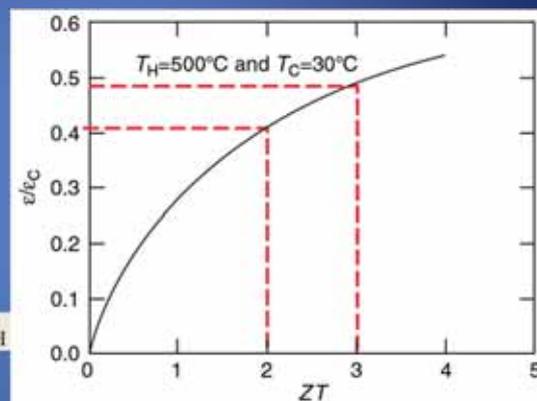
$$\kappa_{el} = L_0 \sigma T$$

- To match a refrigerator, an effective $ZT=4$ is needed
- To efficiently recover waste heat from car, $ZT=2$ is needed

Efficiency and ZT

$$\eta_{TE} = \eta_C \left(\frac{\sqrt{1 + ZT} - 1}{\sqrt{1 + ZT} + \frac{T_C}{T_H}} \right)$$

Carnot efficiency, $\eta_C = (T_H - T_C)/T_H$



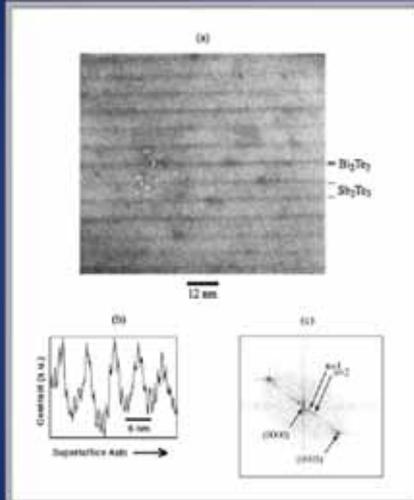
New Approaches

- New Bulk Materials
 - Skutterudites (Rensselaer, Oak Ridge, JPL, 1992)
 - ❖ Cage-structures with rattling atoms to scatter phonons
 - Novel Chalcogenides and Clathrates (Michigan State and Arizona, 1994)
 - ❖ Complex Variations of Bi_2Te_3 to reduce phonon mean-free paths
- Nano-scale Materials
 - Low-Dimensional Structures (MIT, MIT Lincoln Labs, 1992)
 - ❖ Quantum-confinement to Enhance Density of states which increase Seebeck coefficient
 - Nano-scale Superlattices (RTI, 1992)
 - ❖ **Phonon-blocking** from acoustic mismatch between superlattice components but **electron-transmitting** due to negligible electron-energy offsets
 - Heterostructure Thermionics (UCSB, Oak Ridge, 1996)
 - ❖ Thermionic-like effects using energy barriers that can be controlled in hetero-structures

New Progresses

- $\text{Cs Bi}_4\text{Te}_6$ (Michigan State University)
 - Bulk Materials with a ZT~ 0.8 at 225K but less than 0.8 at 300K (*Science* **287**, 1024-1027, 2000)
- Filled Skutterudites (JPL)
 - Bulk materials with a ZT~1.35 at 900K (Proc. Of 15th International Conf. On Thermoelectrics, 1996)
- PbTe/PbTeSe Quantum-dots (Harman, MIT Lincoln Labs.)
 - ZT~ 1.6 at 300K based on cooling data (*Science* 297, Sep. 2002)
- $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ Superlattices (RTI)
 - ZT~2.4 at 300K in devices with all properties measured at the same place, same time, with current flowing and verified by two independent techniques (*Nature*, 597-602, Oct. 2001)

Nanostructured Superlattice

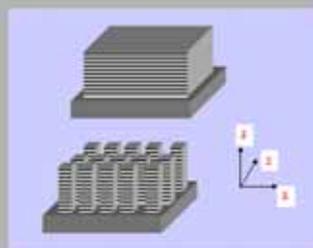


- 10Å/50Å $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ Structure
- Optimized for disrupting heat transport while enhancing electron transport perpendicular to the superlattice interfaces

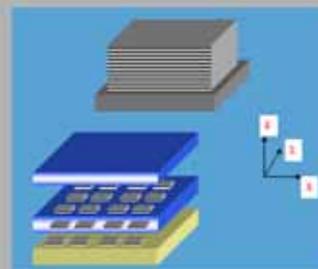
Applied Physics Letters, 75, 1104 (1999)

New Ideas

- Combine Phonon-Blocking, Electron-Transmitting Structures Along Heat Flow with Orthogonal Quantum-Confinement for ZT in the range of 4 to 5?

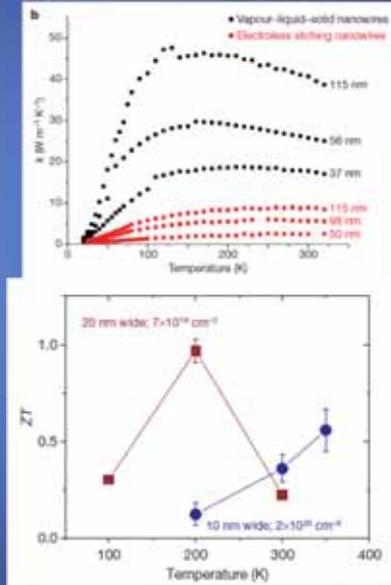
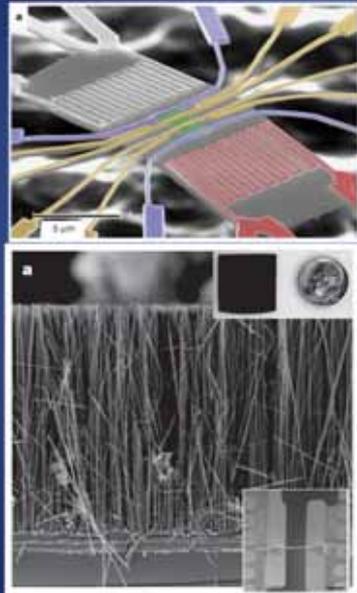


Layered SL Patterned to form 1-d Quantum-Wires – **Orthogonal Quantum Confinement**



Layered SL Patterned to form Quantum-Boxes – **Orthogonal Quantum Confinement**

Si Nanowires as an Efficient TE Material



Akram I. Boukai *et al*, Nature 451 168(2007)

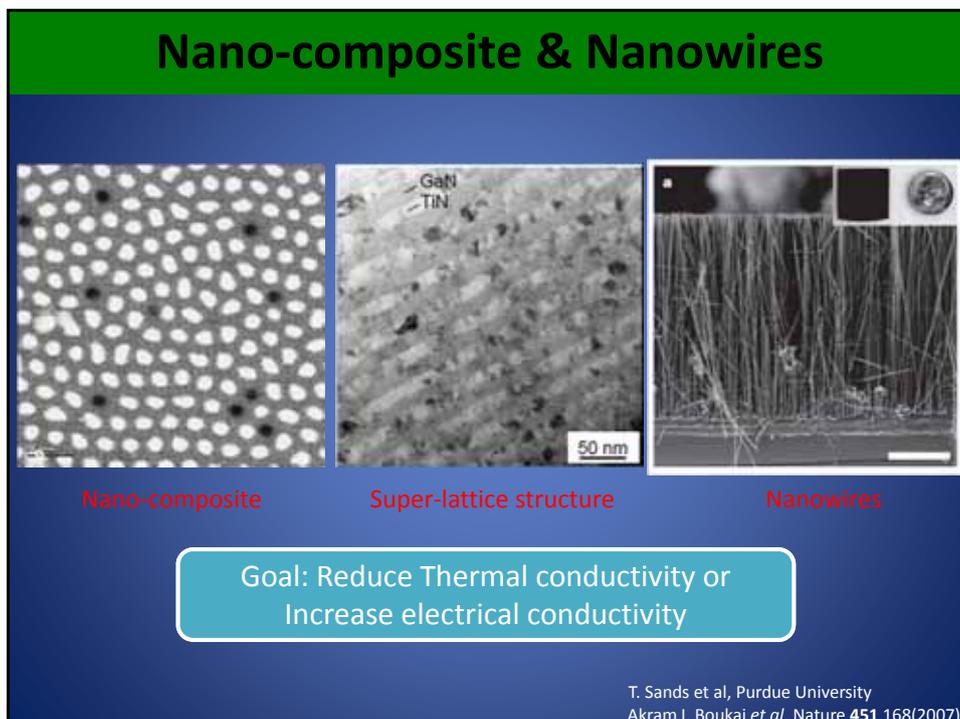
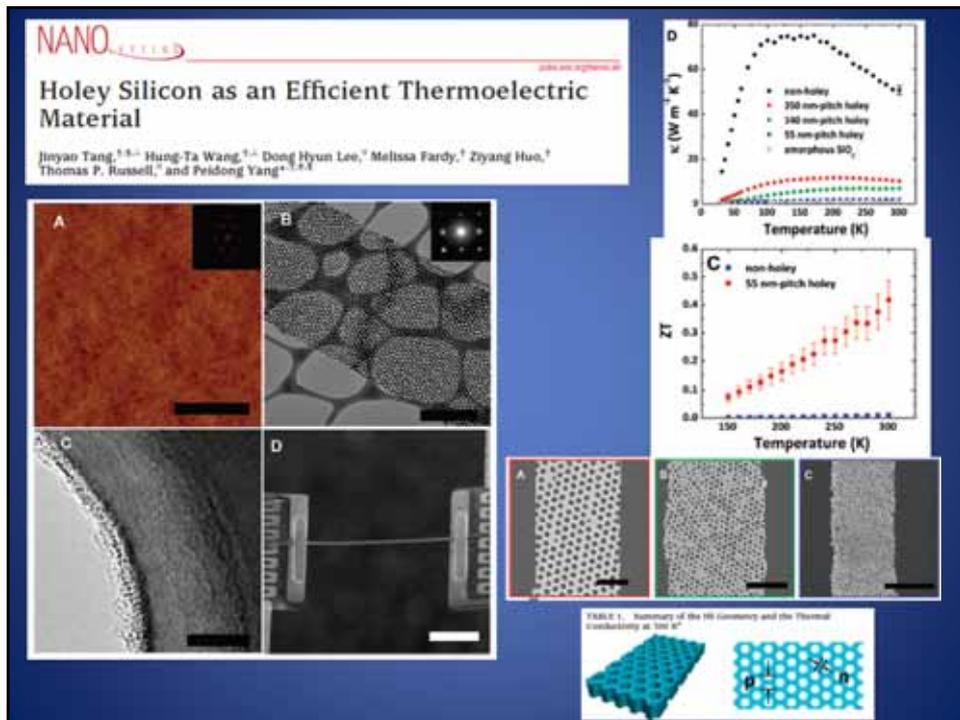
Vol 451 | 10 January 2008 | doi:10.1038/nature06381

Enhanced thermoelectric performance of rough silicon nanowires

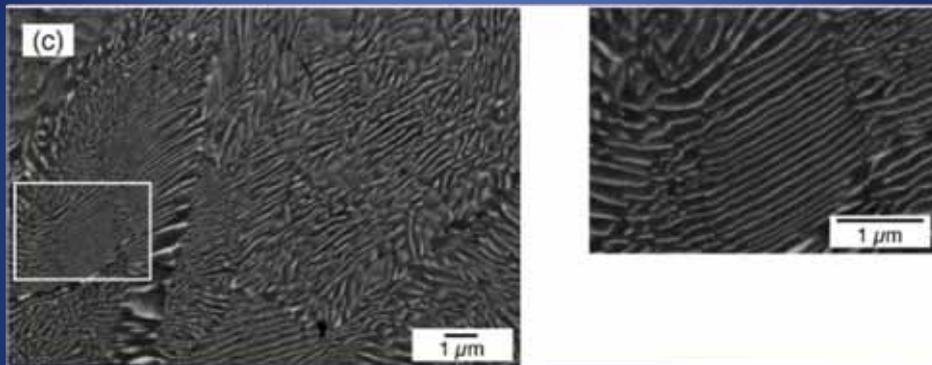
Allon I. Hochbaum^{1*}, Renkun Chen^{2*}, Raul Diaz Delgado¹, Wenjie Liang¹, Erik C. Garnett¹, Mark Najarian³, Arun Majumdar^{3,3,4} & Peidong Yang^{1,3,4}

Aqueous Etching NW

VLS grown NW

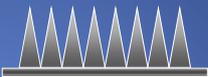
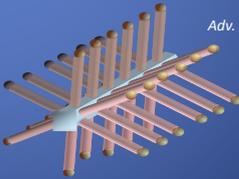


Lamellae of Thermoelectric PbTe and Sb₂Te₃

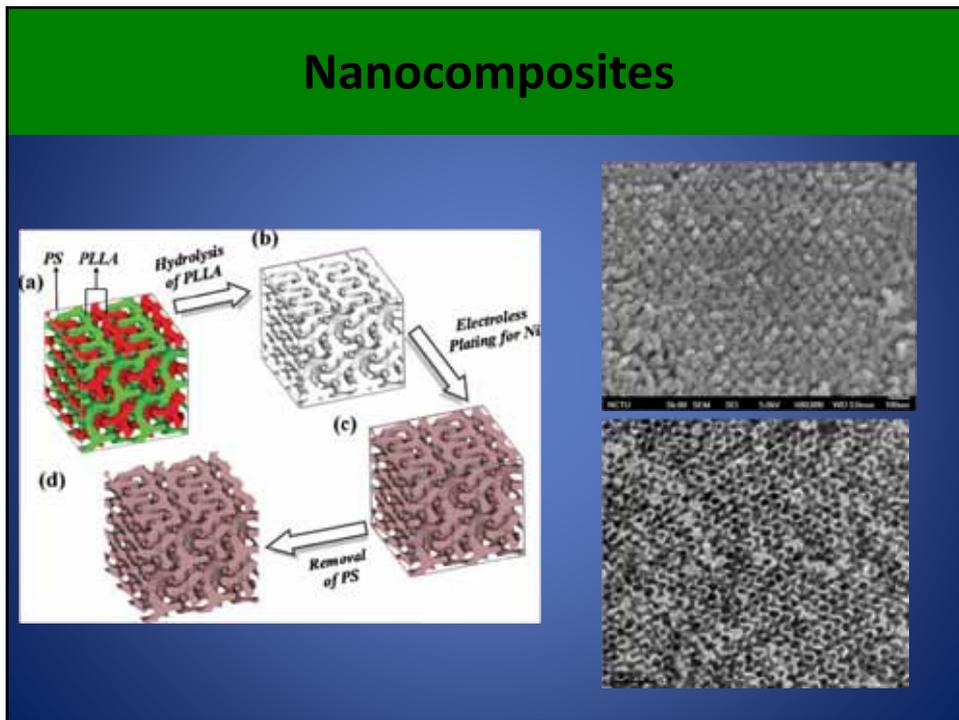


Jeffrey Snyder *Chem. Mater.*, Vol. 19, No. 4, 2007 765

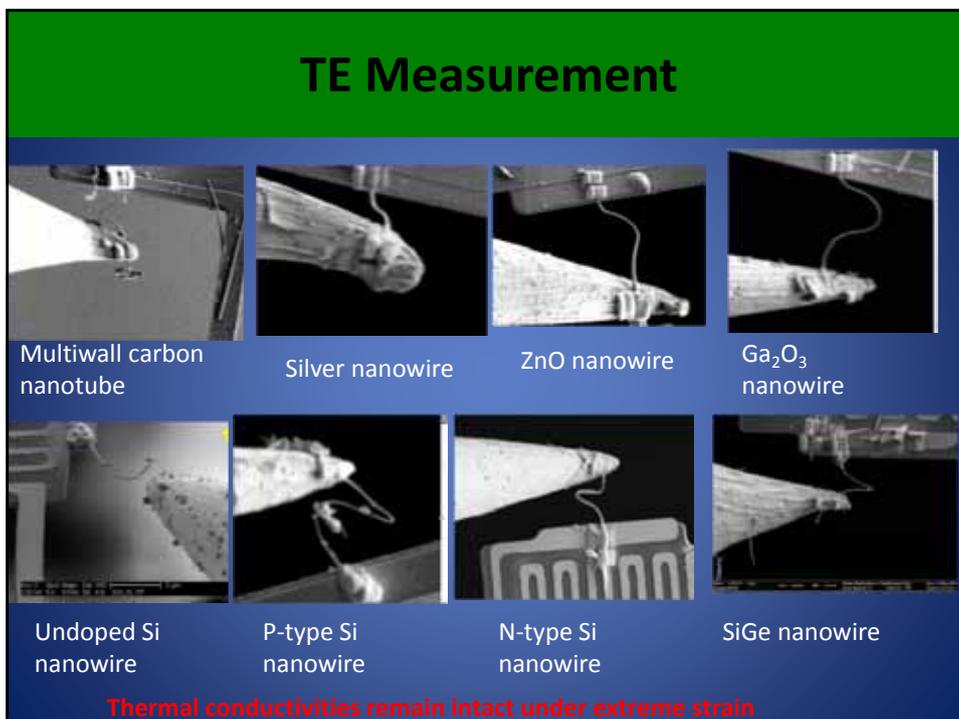
1-D Nano Materials in AML

<p>JACS 123, 2791 (2001) APL 81, 22 (2002) JACS 127, 2820 (2005) APL 90, 213104 (2007) Adv. Func. Mater. (2008) Small 4, 925 (2008) Electrochem. Comm. 11, 850 (2009) Anal. Chem. 81, 36 (2009) Angew. Chem. Int. Ed. 49, 5966 (2010)</p>	 <p>Wire/Rod</p>	 <p>Nanotip</p>	<p>APL 83, 1420 (2003) Nano. Lett. 4, 471 (2004) Chem. Mater. 17, 553 (2005) Adv. Func. Mater. 15, 783 (2005) APL 86, 203119 (2005) US Patent 6,960,528,B2 APL 89, 143105 (2006) Nature Nanotech. 2, 170 (2007) Nano Lett. 9, 1938 (2009)</p>
<p>APL 81, 4189 (2002) Adv. Func. Mater. 12, 687 (2002) APL 86, 203119 (2005) JACS 128, 8368 (2006) PRB 75, 195429 (2007) J. Power Sources 171, 55 (2007) JACS 130, 3543 (2008) J. Power Sources 190, 279 (2009)</p>	 <p>Tube</p>	 <p>Core-shell</p>	<p>APL 81, 1312 (2002) Nano. Lett. 3, 537 (2003)</p>
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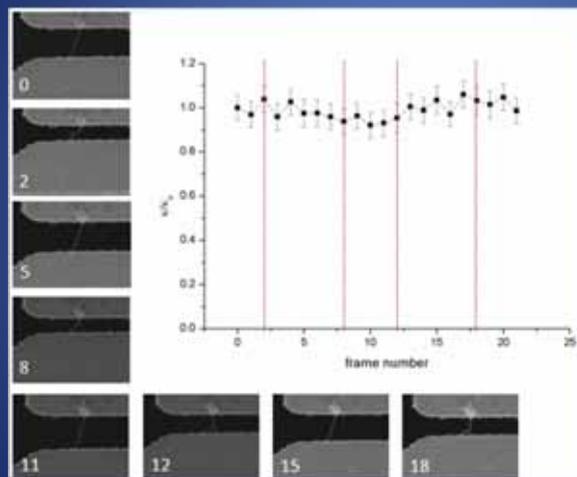
Nanocomposites



TE Measurement



SWCNT goes beyond the theoretical limit of 1D ballistic phonon transport



No changes of thermal conductivity is observed even when the bending radius of curvature is less than the phonon mean free path.

Perspective



- Nanotechnology provides great opportunity for Thermoelectric materials.
- Demonstration of high ZT materials is yet to come.